11. (Amended) A process for production of a sintered oxide ceramic of composition  $Ce_xM_yD_zO_{2-a}$  with dense structure without open porosity or with a predetermined porosity comprising the steps of:

using a first doping element M selected from the group consisting of rear earths, but wherein M ≠ Ce, alkali metals, earth alkali metals, and Ga; using an educt with a second doping element D of at least one metal, but wherein D ≠ M, selected from the group consisting of Cu, Co, Fe, Ni, and Mn wherein second doping element D is of submicron particle size or is a salt solution; and sintering the educts at a temperature between 750-1200°C until a density of at least around 98% of the theoretically possible density is reached to form said oxide ceramic having a grain size no greater than 0.5  $\mu m$  and wherein the mol fractions used range from  $0.5 \le x < 1$  for Ce, 0 < y < 0.5for first doping element M, and 0.0001 < z < 0.05for second doping element D.

18. (Amended) The process according to claim 11 comprising the additional steps of:

monitoring a temperature rise of said composition;